# Contents

<table>
<thead>
<tr>
<th>SESSION 1</th>
<th>VCSEL MODULATION</th>
</tr>
</thead>
<tbody>
<tr>
<td>10938 02</td>
<td>VCSEL modulation speed: status and prospects (Invited Paper) [10938-1]</td>
</tr>
<tr>
<td>10938 03</td>
<td>VCSELs and 100G links (Invited Paper) [10938-2]</td>
</tr>
<tr>
<td>10938 04</td>
<td>Bandwidth and optical output power of VCSELs and VCSEL arrays [10938-3]</td>
</tr>
<tr>
<td>10938 06</td>
<td>The influences of ethernet standards on VCSEL technology (Invited Paper) [10938-5]</td>
</tr>
<tr>
<td>10938 09</td>
<td>Watt-class high-power and high-beam-quality VCSEL amplifiers [10938-8]</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th>SESSION 2</th>
<th>NOVEL VCSEL STRUCTURES</th>
</tr>
</thead>
<tbody>
<tr>
<td>10938 0A</td>
<td>Optically pumped vertical-cavity surface-emitting lasers at 375 nm with air-gap/Al&lt;sub&gt;0.05&lt;/sub&gt;Ga&lt;sub&gt;0.95&lt;/sub&gt;N distributed Bragg reflectors [10938-9]</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th>SESSION 3</th>
<th>COMMERCIAL VCSELS</th>
</tr>
</thead>
<tbody>
<tr>
<td>10938 0C</td>
<td>Temperature characteristics of all monolithically integrated self-scanning VCSEL array [10938-11]</td>
</tr>
<tr>
<td>10938 0D</td>
<td>VCSEL arrays for quasi-continuous-wave applications [10938-12]</td>
</tr>
<tr>
<td>10938 0E</td>
<td>VCSELs in short-pulse operation for time-of-flight applications [10938-13]</td>
</tr>
<tr>
<td>10938 0F</td>
<td>High-power VCSEL arrays with customized beam divergence for 3D-sensing applications [10938-14]</td>
</tr>
<tr>
<td>10938 0G</td>
<td>Tunable vertical-cavity surface-emitting lasers as a light source for diffuse optical spectroscopy [10938-15]</td>
</tr>
</tbody>
</table>
SESSION 4  VCSELs FOR APPLICATIONS

10938 0J  Energy efficient 850-nm VCSEL based optical transmitter and receiver link capable of 56 Gbit/s NRZ operation [10938-18]

SESSION 5  VCSEL PERFORMANCE ANALYSIS

10938 0N  Comprehensive self-consistent analysis of oxide-confined vertical-cavity surface-emitting lasers [10938-22]
Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Agustin, M., 0J
Bacchin, Gianluca, 0D
Black, Matthew K., 0D
Caspar, C., 0J
Chen, Ring, 0A
Chorchos, L., 0J
Cole, G. D., 0G
Detchprohm, Theeradetch, 0A
Dummer, M. M., 0G
Dupuis, Russell D., 0A
Foresi, James, 0D
Ghosh, Chun I, 0F
Gronenborn, Stephan, 0E
Gu, Xiaodong, 0B
Gu, Xi, 0E
Guidde, Ralph, 0E
Guo, Baliming, 0F
Guo, Dingkai, 0F
Gustavsson, J. S., 02
Haghighi, Nasibeh, 04
Haglund, E. P., 02
Haglund, E., 02
Hayakawa, Junichiro, 08
Helms, Chris J., 0D
Herper, Markus, 0E
Ho, Zeuku, 08
Jeong, Hoon, 0A
Jewell, Jack, 06
Johnson, K., 0G
Kalasha, V. P., 0J, 0N
Kitsunoai, Masakazu, 0C
Koep, M., 0J
Kolb, Johanna, 0E
Komagata, Shogo, 0C
Kondo, Takashi, 0C
Koyama, Fumio, 08
Kropp, J.-R., 0J
Larsson, A., 02
Lavrencik, Justin, 03
Ledentsov, Jr., N., 0J, 0N
Ledentsov, N. N., 0J, 0N
Lengyel, T., 02
Liu, Yuh-Shiuan, 0A
Lott, James A., 04
Mehta, Karan A.
Melgar, Alfonso, 03
Miglo, Alexander, 0F
Miller, Michael, 0E
Moench, Holger, 0E
Moser, Philip, 04
Murakami, Akemi, 0B
Ohno, Seiji, 0C
Oktar, Serdal, 0F
Othman, Hasan, 0F
Park, Young Jae, 0A
Ponce, Fernando, 0A
Ralph, Stephen E., 03
Rothwell, S. L., 0G
Schelle, Malik, 0F
Seurin, Jean-Francois, 0F
Shchukin, V. A., 0J, 0N
Shen, Shyh-Chialing, 0A
Simpchen, E., 02
Smeets, Michael, 0E
Suzuki, Yoshiyuki, 08
Toledo, Kevin, 0D
Tominaga, Daiji, 08
Turkiewicz, J. P., 0J
Usami, Hirokazu, 0C
Van Leeuwen, Robert, 0F
Wang, Jiulin, 0A
Wang, Shuo, 0A
Warren, Michael E., 0D
Watkins, Larry, 0F
Weigl, Alexander, 0E
Xu, Guoyang, 0F
Yang, Lei, 0B
Yoder, P. Douglas, 0A
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1 VCSEL Modulation

Luke A. Graham, Dallas Quantum Devices (United States)
2 Novel VCSEL Structures  
    Kent D. Choquette, University of Illinois (United States)

3 Commercial VCSELs  
    James A. Lott, Technische Universität Berlin (Germany)

4 VCSELs for Applications  
    Chun Lei, Lumentum (United States)

5 VCSEL Performance Analysis  
    Luke A. Graham, Dallas Quantum Devices (United States)